

SBR2060CT SBR2060CTF SBR2060CTI SBR2060CTB

Super Barrier Rectifier ™

Using state-of-the-art SBR IC process technology, the following features are made possible in a single device:

Major ratings and characteristics

Characteristics	Values	Units
I _{F(AV)} Rectangular Waveform	20	Α
V_{RRM}	60	٧
V _F @10A, Tj=125 ^O C	0.49	V, typ
Tj (operating/storage)	-65 to 150	°C

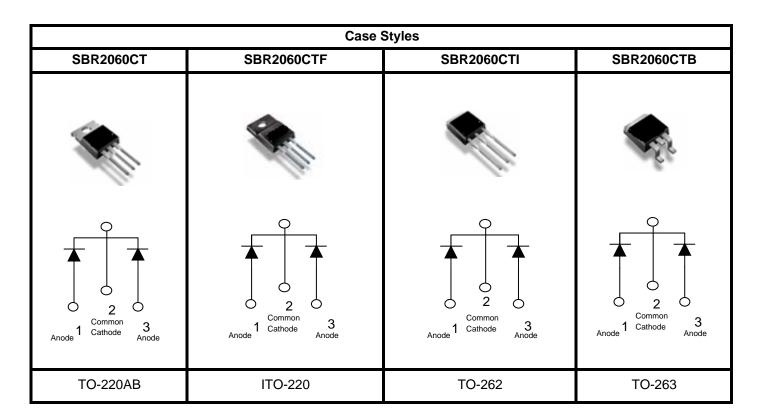
Device optimized for low forward voltage drop to maximize efficiency in Power Supply applications

ELECTRICAL:

- * Low Forward Voltage Drop
- * Reliable High Temperature Operation
- * Super Barrier Design
- * Softest, fast switching capability
- * 150°C Operating Junction Temperature

MECHANICAL:

* Molded Plastic TO-220AB, TO-262, TO-263, and ITO-220 packages





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(at 25 ^o C unless otherwise specified)					
	SYMBOL			UNITS	
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	$egin{array}{c} egin{array}{c} egin{array}{c} V_{RWM} \ V_{RRM} \end{array}$	60		Volts	
Average Rectified Forward Current (Rated V _R -20Khz Square Wave) - 50% duty cycle	Io	20		Amps	
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	150		Amps	
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I _{RRM}	2		Amps	
Instantaneous Forward Voltage (per leg) $I_F = 10A$; $T_J = 25^{\circ}C$ $I_F = 10A$; $T_J = 125^{\circ}C$	V _F	Тур 	Max 0.70 0.65	Volts	
Maximum Instantaneous Reverse Current at Rated V_{RM} $T_J = 25^{\circ}C$ $T_J = 125^{\circ}C$	I _R ·	Тур 	Max 0.5 100	mA mA	
Maximum Rate of Voltage Change (at Rated V _R)	dv/dt	10,000		V/uS	
Maximum Thermal Resistance JC (per leg) Package = TO-220AB, TO-262, & TO-263 Package = ITO-220	R⊕ _{JC}	2 4		°C/W	

NOTE: Dice are available for customer applications.

Operating and Storage Junction Temperature

 T_J

-65 to +150

οС

^{*} Pulse width < 300 uS, Duty cycle < 2%



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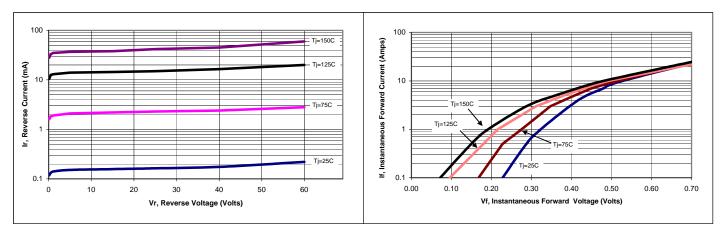


Figure 1: Typical Reverse Current (per leg)

Figure 2: Typical Forward Voltage (per leg)

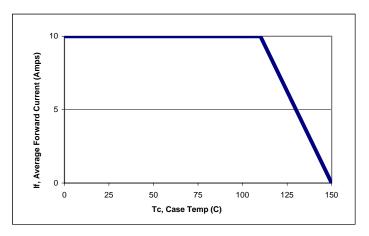
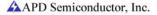


Figure 3: Current Derating, Case (per leg)

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